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TLS205B0

Linear Voltage Post Regulator
Low Dropout, Low Noise, 3.3 V, Adjustable, 500 mA

TLS205B0EJV
TLS205B0EJV33
TLS205B0LDV
TLS205B0LDV33

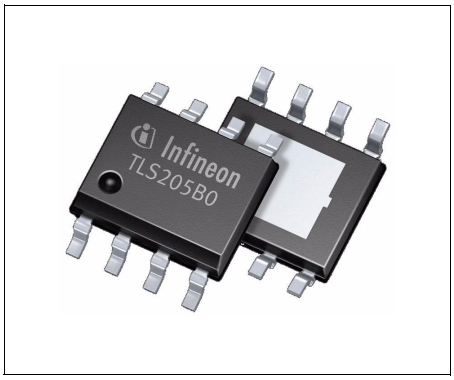
Data Sheet

Rev. 1.2, 2015-01-15

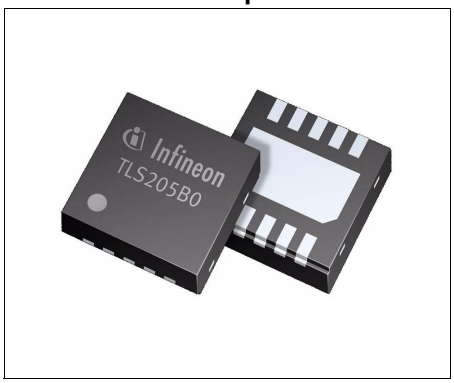
Automotive Power

Linear Voltage Post Regulator **TLS205B0**
Low Dropout, Low Noise, 3.3 V, Adjustable, 500 mA

1 Overview



PG-DSO-8 Exposed Pad



PG-TSON-10

Features

- Low Noise down to 24 μV_{RMS} (BW = 10 Hz to 100 kHz)
- 500 mA Current Capability
- Low Quiescent Current: 30 µA
- Wide Input Voltage Range up to 20 V
- Internal circuitry working down to 2.3 V
- 2.5% Output Voltage Accuracy (over full temperature and load range)
- Low Dropout Voltage: 320 mV
- Very low Shutdown Current: < 1 µA
- No Protection Diodes Needed
- Fixed Output Voltage: 3.3 V
- Adjustable Version with Output from 1.22 V to 20 V
- Stable with ≥ 3.3 µF Output Capacitor
- Stable with Aluminium, Tantalum or Ceramic Output Capacitors
- Reverse Polarity Protection
- No Reverse Current
- Overcurrent and Overtemperature Protected
- PG-DSO-8 Exposed Pad and PG-TSON-10 Exposed Pad Package
- Suitable for Use in Automotive Electronics as Post Regulator
- Green Product (RoHS compliant)
- AEC Qualified

The TLS205B0 is a micropower, low noise, low dropout voltage regulator. The device is capable of supplying an output current of 500 mA with a dropout voltage of 320 mV. Designed for use in battery-powered systems, the low quiescent current of 30 µA makes it an ideal choice.

A key feature of the TLS205B0 is its low output noise. By adding an external 10 nF bypass capacitor output noise values down to 24 μV_{RMS} over a 10 Hz to 100 kHz bandwidth can be reached. The TLS205B0 voltage regulator

Type	Package	Marking
TLS205B0EJV	PG-DSO-8 Exposed Pad	205B0V
TLS205B0EJV33	PG-DSO-8 Exposed Pad	205B0V33
TLS205B0LDV	PG-TSON-10	205B0V
TLS205B0LDV33	PG-TSON-10	205B0V3

is stable with output capacitors as small as 3.3 µF. Small ceramic capacitors can be used without the series resistance required by many other linear voltage regulators.

Internal protection circuitry includes reverse battery protection, current limiting and reverse current protection. The TLS205B0 comes as fixed output voltage variant 3.3 V as well as adjustable device with a 1.22 V reference voltage. It is available in a PG-DSO-8 Exposed Pad and as well as in a PG-TSON-10 Exposed Pad package.

2 Block Diagram

Note: Pin numbers in block diagrams refer to the PG-DSO-8 Exposed Pad package type.

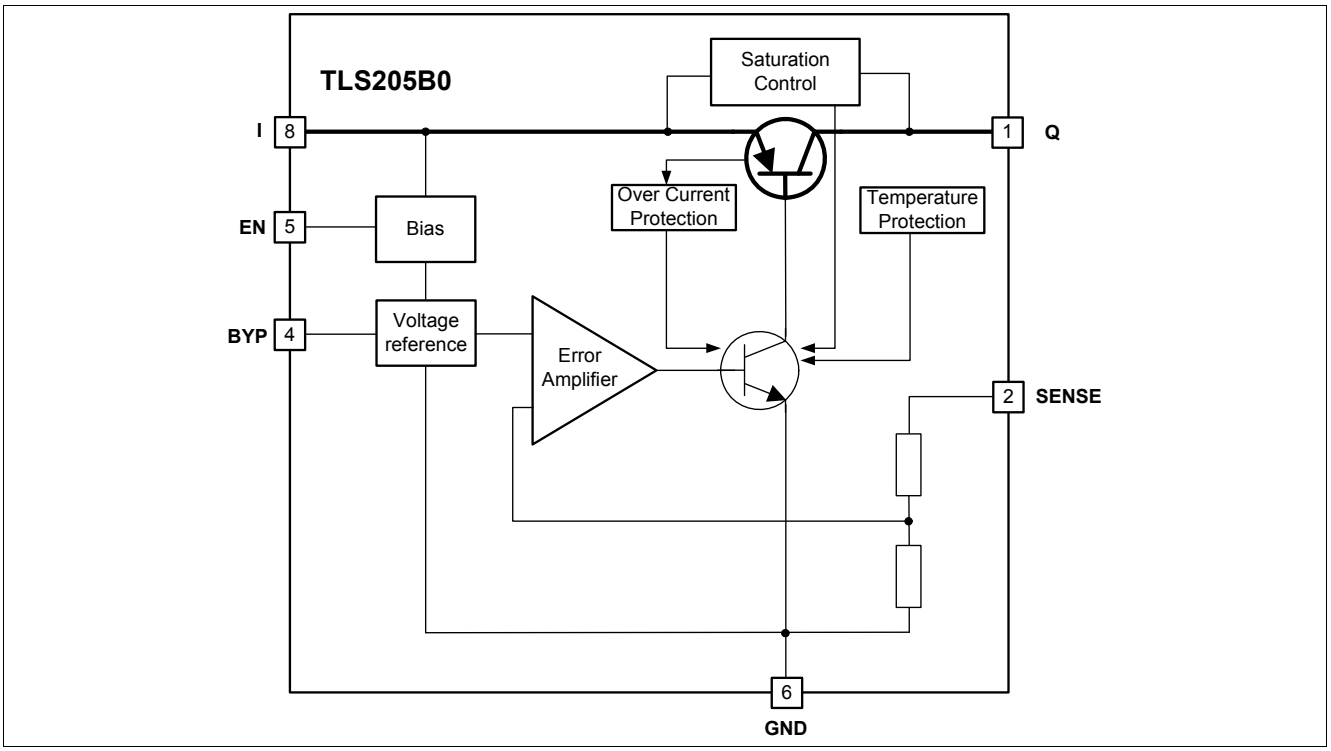


Figure 1 Block Diagram TLS205B0 V33 fixed voltage version

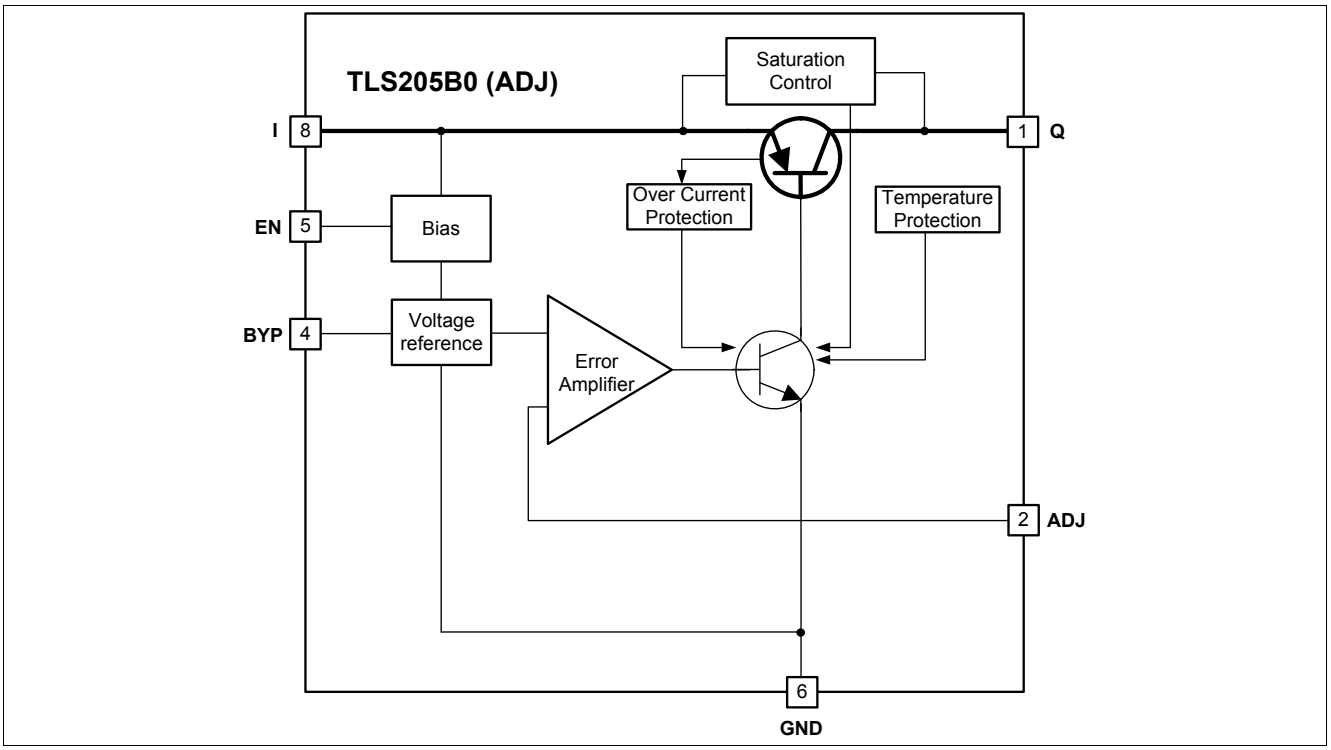


Figure 2 Block Diagram TLS205B0 V adjustable version

3 Pin Configuration

3.1 Pin Assignment

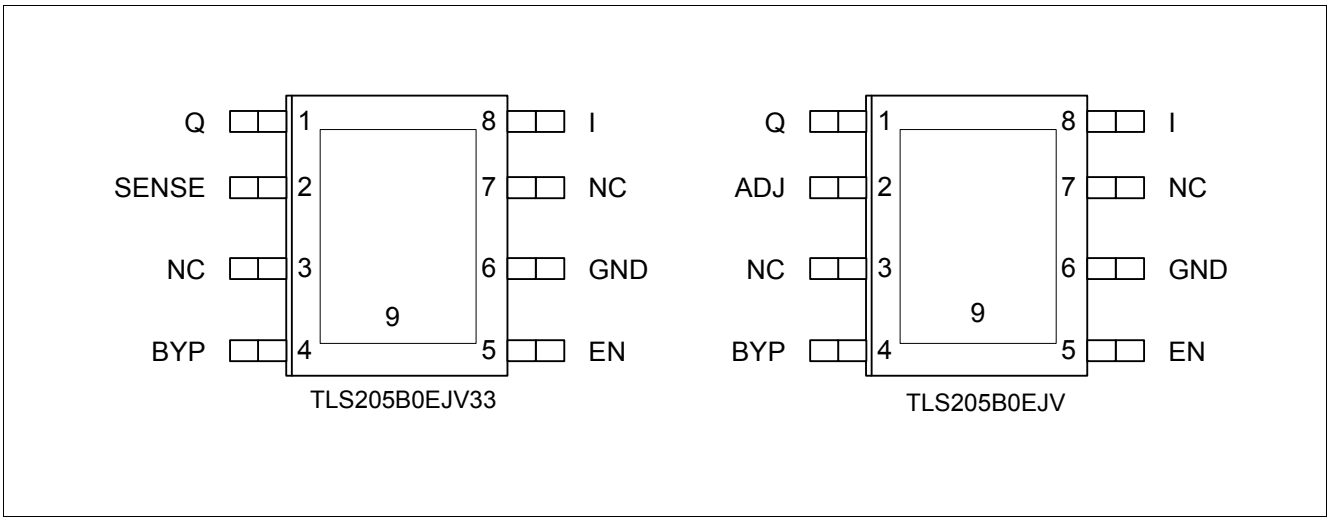


Figure 3 Pin Configuration of TLS205B0 in PG-DSO-8 Exposed Pad for fixed voltage and adjustable version

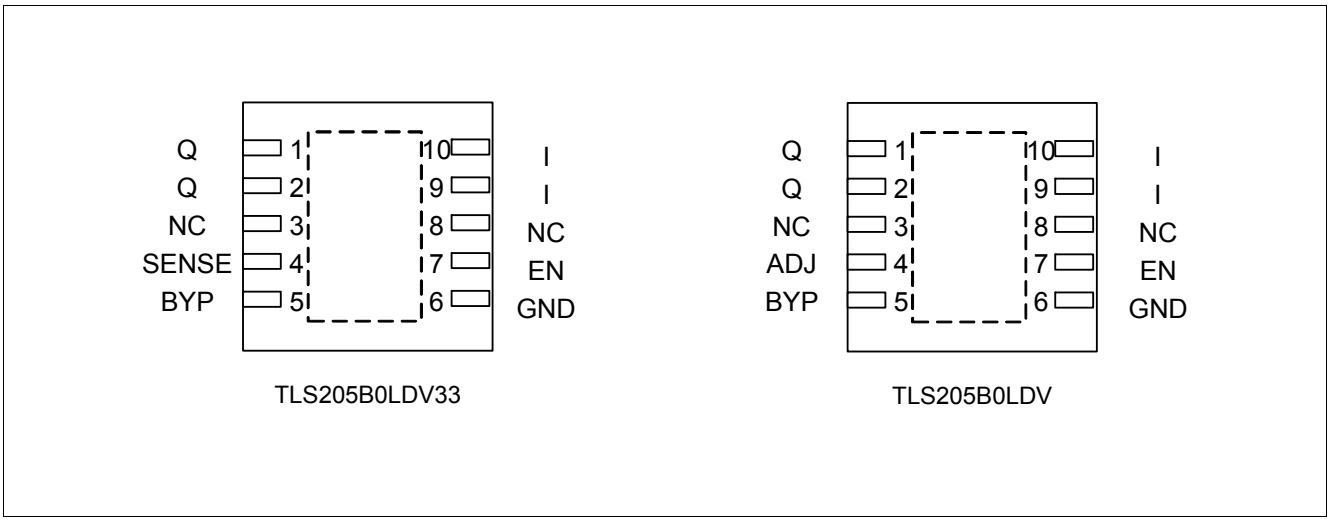


Figure 4 Pin Configuration of TLS205B0 in PG-TSON-10 for fixed voltage and adjustable version

3.2 Pin Definitions and Functions

Pin	Symbol	Function
1 (DSO-8 EP) 1,2 (TSON-10)	Q	**Output.** Supplies power to the load. For this pin a minimum output capacitor of 3.3 µF is required to prevent oscillations. Larger output capacitors may be required for applications with large transient loads in order to limit peak voltage transients or when the regulator is applied in conjunction with a bypass capacitor. For more details please refer to **"Application Information" on Page 24**.
2 (DSO-8 EP) 4 (TSON-10)	SENSE (fix voltage version)	**Output Sense.** For the fixed voltage version the SENSE pin is the input to the error amplifier. This allows to achieve an optimized regulation performance in case of small voltage drops R_p that occur between regulator and load. In applications where such drops are relevant they can be eliminated by connecting the SENSE pin directly at the load. In standard configuration the SENSE pin can be directly connected to Q. For further details please refer to the section **"Kelvin Sense Connection" on Page 25**.
2 (DSO-8 EP) 4 (TSON-10)	ADJ (adjustable version)	**Adjust.** For the adjustable version the ADJ pin is the input to the error amplifier. The ADJ pin voltage is 1.22 V referenced to ground and allows a output voltage range from 1.22 V to 20 V- V_{DR}. The ADJ pin is internally clamped to ±7 V. Please note that the bias current of the ADJ pin is flowing into the pin. Its typical value of 60 nA shows a good stability with temperature. For further details please refer to Typical Performance Graph **"Adjust Pin Bias Current versus Junction Temperature T_J" on Page 20**.
3, 7 (DSO-8 EP) 3, 8 (TSON-10)	NC	**No Connect.** The NC Pins have no connection to any internal circuitry. Connect either to GND or leave open.
4 (DSO-8 EP) 5 (TSON-10)	BYP	**Bypass.** The BYP pin is used to bypass the reference of the TLS205B0 to achieve low noise performance. The BYP-pin is clamped internally to ±0.6 V (i.e. one V_{BE}). A small capacitor from the output Q to the BYP pin will bypass the reference to lower the output voltage noise [1]. If not used this pin must be left unconnected.
5 (DSO-8 EP) 7 (TSON-10)	EN	**Enable.** With the EN pin the TLS205B0 can be put into a low power shutdown state. The output will be off when the EN is pulled low. The EN pin can be driven either by 3.3 V or 5 V logic or as well by open-collector logic with pull-up resistor. The pull-up resistor is required to supply the pull-up current of the open-collector gate [2] and the EN pin current [3]. Please note that if the EN pin is not used it must be connected to V_I. It must not be left floating.
6 (DSO-8 EP) 6 (TSON-10)	GND	**Ground.** For the ADJ version connect the bottom of the output voltage setting resistor divider directly to the GND pin for optimum load regulation performance.

Pin	Symbol	Function
8 (DSO-8 EP) 9, 10 (TSON-10)	I	**Input.** The device is supplied by the input pin I. A capacitor at the input pin is required if the device is more than 6 inches away from the main input filter capacitor or if a non-negligible inductance is present at the input I [4]. The TLS205B0 is designed to withstand reverse voltages on the input pin I with respect to GND and output Q. In the case of reverse input (e.g. due to a wrongly attached battery) the device will act as if there is a diode in series with its input. In this way there will be no reverse current flowing into the regulator and no reverse voltage will appear at the load. Hence, the device will protect both - the device itself and the load.
9 (DSO-8 EP) 11 (TSON-10)	Tab	**Exposed Pad.** To ensure proper thermal performance, solder Pin 11 of TSON-10 to the PCB ground and tie directly to Pin 6. In the case of DSO-8 EP as well solder Pin 9 to the PCB ground and tie directly to Pin 6 (GND).

1) A maximum value of 10 nF can be used for reducing output voltage noise over the bandwidth from 10 Hz to 100 kHz.

2) Normally several microamperes.

3) Typical value is 1 µA.

4) In general the output impedance of a battery rises with frequency, so it is advisable to include a bypass capacitor in battery-powered circuits. Depending on actual conditions an input capacitor in the range of 1 to 10 µF is sufficient.

4 General Product Characteristics

4.1 Absolute Maximum Ratings

Table 1 Absolute Maximum Ratings [1)]

T_j = -40 °C to +150 °C; all voltages with respect to ground, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Typ.	Max.			
Input Voltage							
Voltage	V_I	-20	–	20	V	–	P_4.1.1
Output Voltage							
Voltage	V_Q	-20	–	20	V	–	P_4.1.2
Input to Output Differential Voltage	V_I - V_Q	-20	–	20	V	–	P_4.1.3
Sense Pin							
Voltage	V_{SENSE}	-20	–	20	V	–	P_4.1.4
ADJ Pin							
Voltage	V_{ADJ}	-7	–	7	V	–	P_4.1.5
BYP Pin							
Voltage	V_{BYP}	-0.6	–	0.6	V		P_4.1.6
Enable Pin							
Voltage	V_{EN}	-20	–	20	V	–	P_4.1.7
Temperatures							
Junction Temperature	T_j	-40	–	150	°C	–	P_4.1.8
Storage Temperature	T_{stg}	-55	–	150	°C	–	P_4.1.9
ESD Susceptibility							
All Pins	V_{ESD}	-2	–	2	kV	HBM [2)]	P_4.1.10
All Pins	V_{ESD}	-1	–	1	kV	CDM [3)]	P_4.1.11

1) Not subject to production testing, specified by design.

2) ESD susceptibility, HBM according to ANSI/ESDA/JEDEC JS001 (1.5 kΩ, 100 pF)

3) ESD susceptibility, Charged Device Model “CDM” according JEDEC JESD22-C101

Notes

1. *Stresses above the ones listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.*
2. *Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as “outside” normal operating range. Protection functions are not designed for continuous repetitive operation.*

4.2 Functional Range

Table 2 Functional Range

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Typ.	Max.			
Input Voltage Range (fix voltage version)	V_I	3.8 V	–	20	V	–	P_4.2.1
Input Voltage Range (adjustable voltage version)	V_I	2.3	–	20	V	–[1)]	P_4.2.2
Output Capacitor's Requirements for Stability	C_Q	3.3	–	–	µF	C_{BYP} = 0 nF [2)]	P_4.2.3
Output Capacitor's Requirements for Stability	C_Q	6.8	–	–	µF	$0 < C_{BYP} \leq 10$ nF [2)]	P_4.2.4
ESR	ESR	–[3)]	–	3	Ω	– [2)]	P_4.2.5
Operating Junction Temperature	T_j	-40	–	125	°C	–	P_4.2.6

1) For the TLS205B0 adjustable version the minimum limit of the functional range V_I is tested and specified with the ADJ- pin connected to the Q pin.

2) for further details see corresponding graph.

3) C_{BYP} = 0 nF, $C_Q \geq$ 3.3 µF; please note that for cases where a bypass capacitor at BYP is used – depending on the actual applied capacitance of C_Q and C_{BYP} a minimum requirement for ESR of C_Q may apply.

Note: Within the functional or operating range, the IC operates as described in the circuit description. The electrical characteristics are specified within the conditions given in the Electrical Characteristics table.

4.3 Thermal Resistance

*Note: This thermal data was generated in accordance with JEDEC JESD51 standards. For more information, go to **www.jedec.org**.*

Table 3 Thermal Resistance [1)]

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Typ.	Max.			
TLS205B0EJ (PG-DSO-8 Exposed Pad)							
Junction to Case	R_{thJC}	–	7.0	–	K/W	–	P_4.3.1
Junction to Ambient	R_{thJA}	–	39	–	K/W	– [2)]	P_4.3.2
Junction to Ambient	R_{thJA}	–	155	–	K/W	Footprint only [3)]	P_4.3.3
Junction to Ambient	R_{thJA}	–	66	–	K/W	300 mm² heatsink area on PCB [3)]	P_4.3.4
Junction to Ambient	R_{thJA}	–	52	–	K/W	600 mm² heatsink area on PCB [3)]	P_4.3.5
TLS205B0LD (PG-TSON-10)							
Junction to Case	R_{thJC}	–	6.4	–	K/W	–	P_4.3.6
Junction to Ambient	R_{thJA}	–	53	–	K/W	– [2)]	P_4.3.7
Junction to Ambient	R_{thJA}	–	183	–	K/W	Footprint only [3)]	P_4.3.8

Table 3 Thermal Resistance [1)]

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Typ.	Max.			
Junction to Ambient	R_{thJA}	–	69	–	K/W	300 mm^2 heatsink area on PCB [3)]	P_4.3.9
Junction to Ambient	R_{thJA}	–	57	–	K/W	600 mm^2 heatsink area on PCB [3)]	P_4.3.10

1) Not subject to production test, specified by design.

2) Specified R_{thJA} value is according to Jedec JESD51-2,-5,-7 at natural convection on FR4 2s2p board; The Product (Chip+Package) was simulated on a 76.2 x 114.3 x 1.5 mm board with 2 inner copper layers (2 x 70 µm Cu, 2 x 35 µm Cu). Where applicable a thermal via array under the exposed pad contacted the first inner copper layer.

3) Specified R_{thJA} value is according to JEDEC JESD 51-3 at natural convection on FR4 1s0p board; The Product (Chip+Package) was simulated on a 76.2 × 114.3 × 1.5 mm^3 board with 1 copper layer (1 x 70 µm Cu).

5 Electrical Characteristics

Table 4 Electrical Characteristics

-40 °C < T_j < 125 °C; all voltages with respect to ground; positive current defined flowing out of pin; unless otherwise specified.

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Typ.	Max.			
Minimum Operating Voltage [1]							
Minimum Operating Voltage	$V_{I,min}$	–	1.8	2.3	V	I_Q = 500 mA [2] [3]	P_5.0.1
Output Voltage [4]							
TLS205B0EJV33 TLS205B0LDV33	V_Q	3.220	3.30	3.380	V	1 mA < I_Q < 500 mA ; 4.3 V < V_I < 20 V	P_5.0.2
TLS205B0EJV TLS205B0LDV	V_Q	1.190	1.220	1.250	V	1 mA < I_Q < 500 mA ; 2.3V < V_I < 20 V [3]	P_5.0.3
Line Regulation							
TLS205B0EJV33 TLS205B0LDV33	ΔV_Q	–	1	20	mV	ΔV_I = 3.8 V to 20 V ; I_Q = 1 mA	P_5.0.4
TLS205B0EJV TLS205B0LDV	ΔV_Q	–	1	20	mV	ΔV_I = 2.0 V to 20 V ; I_Q = 1 mA [3]	P_5.0.5
Load Regulation							
TLS205B0EJV33 TLS205B0LDV33	ΔV_Q	–	9	22	mV	T_J = 25 °C;V_I = 4.3 V ; ΔI_Q = 1 to 500 mA	P_5.0.6
TLS205B0EJV33 TLS205B0LDV33	ΔV_Q	–	–	38	mV	V_I = 4.3 V ; ΔI_Q = 1 to 500 mA	P_5.0.7
TLS205B0EJV TLS205B0LDV	ΔV_Q	–	4	8	mV	T_J = 25 °C ; V_I = 2.3 V ; ΔI_Q = 1 to 500 mA [3]	P_5.0.8
TLS205B0EJV TLS205B0LDV	ΔV_Q	–	–	14	mV	V_I = 2.3 V ; ΔI_Q = 1 to 500 mA [3]	P_5.0.9
Dropout Voltage [2] [5] [6]							
Dropout Voltage	V_{DR}	–	130	190	mV	I_Q = 10 mA ; V_I = $V_{Q,nom}$; T_J = 25 °C	P_5.0.10
Dropout Voltage	V_{DR}	–	–	250	mV	I_Q = 10 mA ; V_I = $V_{Q,nom}$	P_5.0.11
Dropout Voltage	V_{DR}	–	170	220	mV	I_Q = 50 mA ; V_I = $V_{Q,nom}$; T_J = 25 °C	P_5.0.12
Dropout Voltage	V_{DR}	–	–	320	mV	I_Q = 50 mA ; V_I = $V_{Q,nom}$	P_5.0.13
Dropout Voltage	V_{DR}	–	200	240	mV	I_Q = 100 mA ; V_I = $V_{Q,nom}$; T_J = 25 °C	P_5.0.14
Dropout Voltage	V_{DR}	–	–	340	mV	I_Q = 100 mA ; V_I = $V_{Q,nom}$	P_5.0.15
Dropout Voltage	V_{DR}	–	320	350	mV	I_Q = 500 mA ; V_I = $V_{Q,nom}$; T_J = 25 °C	P_5.0.16
Dropout Voltage	V_{DR}	–	–	450	mV	I_Q = 500 mA ; V_I = $V_{Q,nom}$	P_5.0.17
Quiescent Current							
Quiescent Current [5] [7] (Active-Mode, EN-pin high)	I_q	–	30	60	µA	V_I = $V_{Q,nom}$; I_Q = 0 mA	P_5.0.18

Table 4 Electrical Characteristics (cont'd)

-40 °C < T_j < 125 °C; all voltages with respect to ground; positive current defined flowing out of pin; unless otherwise specified.

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Typ.	Max.			
Quiescent Current (Off-Mode, EN-pin low)	I_q	–	0.1	1	µA	V_I = 6 V ; V_{EN} = 0 V ; T_J = 25 °C	P_5.0.19
GND Pin Current [5) 7)]							
GND Pin Current	I_{GND}	–	50	100	µA	V_I = $V_{Q,nom}$; I_Q = 1 mA	P_5.0.20
GND Pin Current	I_{GND}	–	300	850	µA	V_I = $V_{Q,nom}$; I_Q = 50 mA	P_5.0.21
GND Pin Current	I_{GND}	–	0.7	2.2	mA	V_I = $V_{Q,nom}$; I_Q = 100 mA	P_5.0.22
GND Pin Current	I_{GND}	–	3	8	mA	V_I = $V_{Q,nom}$; I_Q = 250 mA	P_5.0.23
GND Pin Current	I_{GND}	–	11	22	mA	V_I = $V_{Q,nom}$; I_Q = 500 mA ; T_J ≥ 25 °C	P_5.0.24
GND Pin Current	I_{GND}	–	11	31	mA	V_I = $V_{Q,nom}$; I_Q = 500 mA; T_J < 25 °C	P_5.0.25
Enable							
Enable Threshold High	$V_{th,EN}$	–	0.8	2.0	V	V_Q = Off to On	P_5.0.26
Enable Threshold Low	$V_{tl,EN}$	0.25	0.65	–	V	V_Q = On to Off	P_5.0.27
EN Pin Current [8)]	I_{EN}	–	0.01	–	µA	V_{EN} = 0 V ; T_J = 25 °C	P_5.0.28
EN Pin Current [8)]	I_{EN}	–	1	–	µA	V_{EN} = 20V ; T_J = 25 °C	P_5.0.29
Adjust Pin Bias Current [9) 10)]							
ADJ Pin Bias Current	$I_{bias,ADJ}$	–	60	–	nA	T_J = 25 °C	P_5.0.30
Output Voltage Noise [10)]							
Output Voltage Noise TLS205B0EJV [11)] TLS205B0LDV [11)]	e_{no}	–	41	–	μV_{RMS}	C_Q = 10 µF ; C_{BYP} = 10 nF ; I_Q = 500 mA ; BW = 10 Hz to 100 kHz	P_5.0.31
Output Voltage Noise TLS205B0EJV [11)] TLS205B0LDV [11)]	e_{no}	–	28	–	μV_{RMS}	C_Q = 10 µF +250mΩ resistor in series; C_{BYP} = 10 nF ; I_Q = 500 mA ; BW = 10 Hz to 100 kHz	P_5.0.32
Output Voltage Noise TLS205B0EJV [11)] TLS205B0LDV [11)]	e_{no}	–	29	–	μV_{RMS}	C_Q = 22 µF C_{BYP} = 10 nF ; I_Q = 500 mA ; BW = 10 Hz to 100 kHz	P_5.0.33
Output Voltage Noise TLS205B0EJV [11)] TLS205B0LDV [11)]	e_{no}	–	24	–	μV_{RMS}	C_Q = 22 µF +250mΩ resistor in series; C_{BYP} = 10 nF ; I_Q = 500 mA ; BW = 10 Hz to 100 kHz	P_5.0.34

Table 4 Electrical Characteristics (cont'd)

-40 °C < T_j < 125 °C; all voltages with respect to ground; positive current defined flowing out of pin; unless otherwise specified.

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Typ.	Max.			
Output Voltage Noise TLS205B0EJV33 TLS205B0LDV33	e_{no}	–	45	–	μV_{RMS}	C_Q = 10 µF ; C_{BYP} = 10 nF ; I_Q = 500 mA ; BW = 10 Hz to 100 kHz	P_5.0.35
Output Voltage Noise TLS205B0EJV33 TLS205B0LDV33	e_{no}	–	35	–	μV_{RMS}	C_Q = 10 µF +250mΩ resistor in series; C_{BYP} = 10 nF ; I_Q = 500 mA ; BW = 10 Hz to 100 kHz	P_5.0.36
Output Voltage Noise TLS205B0EJV33 TLS205B0LDV33	e_{no}	–	33	–	μV_{RMS}	C_Q = 22 µF C_{BYP} = 10 nF ; I_Q = 500 mA ; BW = 10 Hz to 100 kHz	P_5.0.37
Output Voltage Noise TLS205B0EJV33 TLS205B0LDV33	e_{no}	–	30	–	μV_{RMS}	C_Q = 22 µF +250mΩ resistor in series; C_{BYP} = 10 nF ; I_Q = 500 mA ; BW = 10 Hz to 100 kHz	P_5.0.38
Power Supply Ripple Rejection [10]							
Power Supply Ripple Rejection	$PSRR$	–	65	–	dB	V_I - V_Q = 1.5 V (avg) ; V_{RIPPLE} = 0.5 Vpp ; f_r = 120 Hz ; I_Q = 500 mA	P_5.0.39
Output Current Limitation							
Output Current Limit	$I_{Q,limit}$	520	–	–	mA	V_I = 7 V ; V_Q = 0 V	P_5.0.40
Output Current Limit	$I_{Q,limit}$	520	–	–	mA	V_I = $V_{Q,nom}$ + 1 V or 2.3 V [12] ; ΔV_Q = -0.1 V	P_5.0.41
Input Reverse Leakage Current							
Input Reverse Leakage	$I_{leak,rev}$	–	–	1	mA	V_I = -20 V ; V_Q = 0 V	P_5.0.42
Reverse Output Current [13]							
Fixed Voltage Version	$I_{Reverse}$	–	10	20	µA	V_Q = $V_{Q,nom}$; V_I < $V_{Q,nom}$; T_J = 25 °C	P_5.0.43
Adjustable Voltage Version	$I_{Reverse}$	–	5	10	µA	V_Q = 1.22 V ; V_I < 1.22 V ; T_J = 25 °C [3]	P_5.0.44

1) This parameter defines the minimum input voltage for which the device is powered up and provides the maximum nominal output current of 500 mA. The output voltage of the adjustable version in this condition depends on the chosen setting of the external voltage divider as well as on the applied conditions – thus the device is either regulating its nominal output voltage or is in tracking mode.The 3.3 V fixed voltage version is by definition in tracking mode for such low input voltages.

2) For the adjustable version of the TLS205B0 the dropout voltage for certain output voltage / load conditions will be restricted by the minimum input voltage specification.

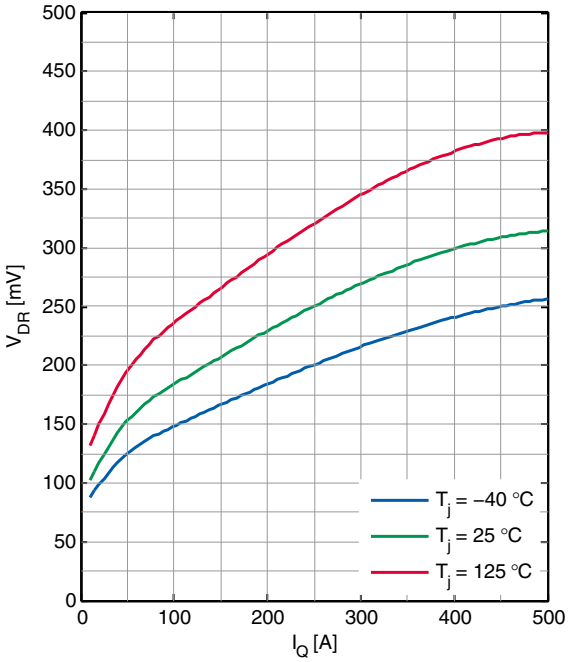
3) The adjustable version of the TLS205B0 is tested / specified for these conditions with the ADJ pin connected to the Q pin.

4) The operation conditions are limited by the maximum junction temperature. The regulated output voltage specification will only apply for conditions where the limit of the maximum junction temperature is fulfilled. It will therefore not apply for all possible combinations of input voltage and output current at a given output voltage. When operating at maximum input voltage, the output current must be limited for thermal reasons. The same holds true when operating at maximum output current where the input voltage range must be limited for thermal reasons.
5) To satisfy requirements for minimum input voltage, the TLS205B0 adjustable version is tested and specified for these conditions with an external resistor divider (two 250 k resistors) for an output voltage of 2.44 V. The external resistors will add a 5 µA DC load on the output.
6) The dropout voltage is the minimum input to output voltage differential needed to maintain regulation at a specified output current. In dropout, the output voltage will be equal to V_I - V_{DR}
7) GND-pin current is tested with V_I = $V_{Q,nom}$ and a current source load. This means that this parameter is tested while being in the dropout region. The GND pin current will in most cases decrease slightly at higher input voltages - please also refer to the corresponding typical performance graphs.
8) The EN pin current flows into EN pin.
9) The ADJ pin current flows into ADJ pin.
10) Not subject to production test, specified by design.
11) ADJ pin connected to output pin Q.
12) Whichever of the two values of V_I is greater in order to also satisfy the requirements for $V_{I,min}$.
13) Reverse output current is tested with the I pin grounded and the Q pin forced to the rated output voltage. This current flows into the Q pin and out of the GND pin.

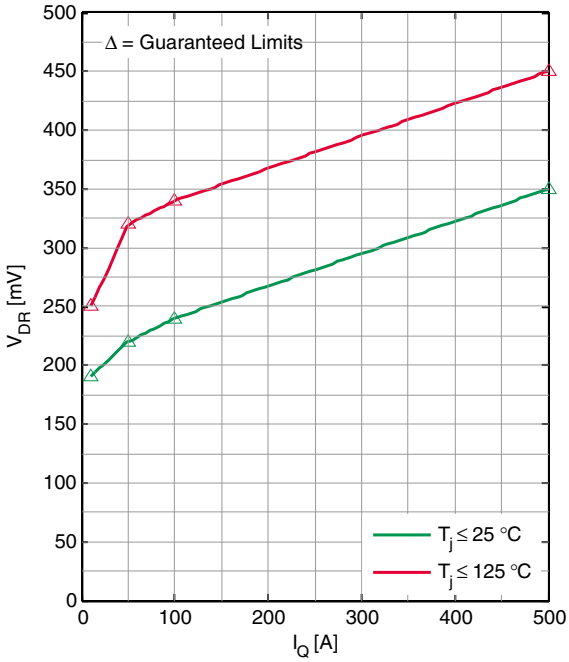
Note: The listed characteristics are ensured over the operating range of the integrated circuit. Typical characteristics specified mean values expected over the production spread. If not otherwise specified, typical characteristics apply at T_A = 25 °C and the given supply voltage.

5.1 Typical Performance Characteristics

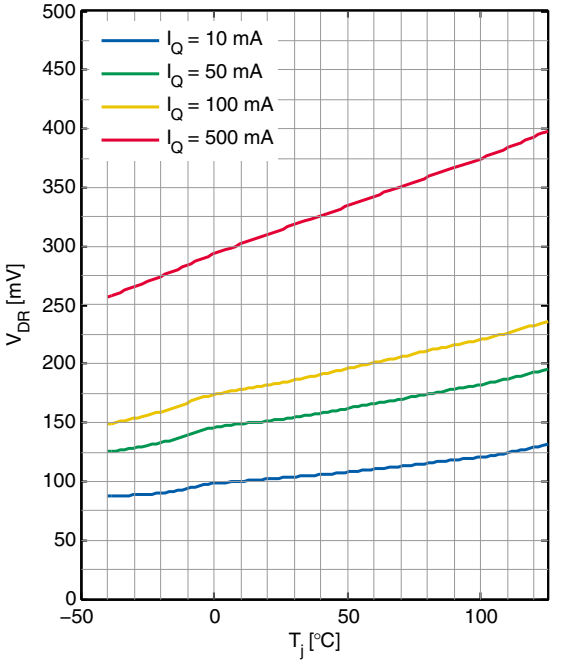
Dropout Voltage V_{DR} versus Output Current I_Q



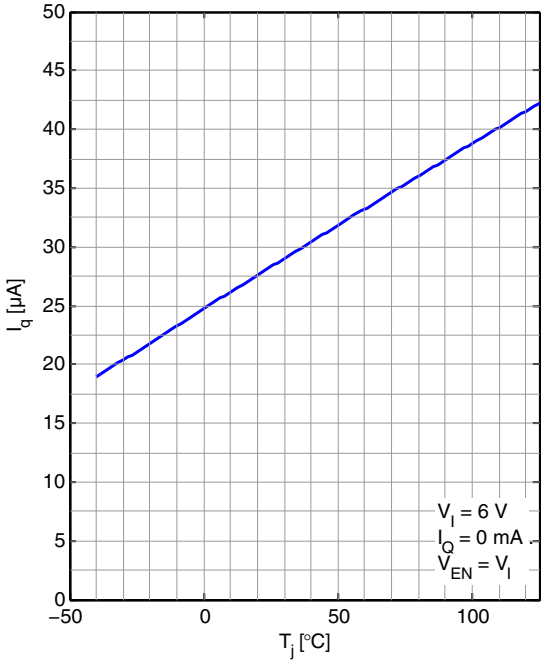
Guaranteed Dropout Voltage V_{DR} versus Output Current I_Q



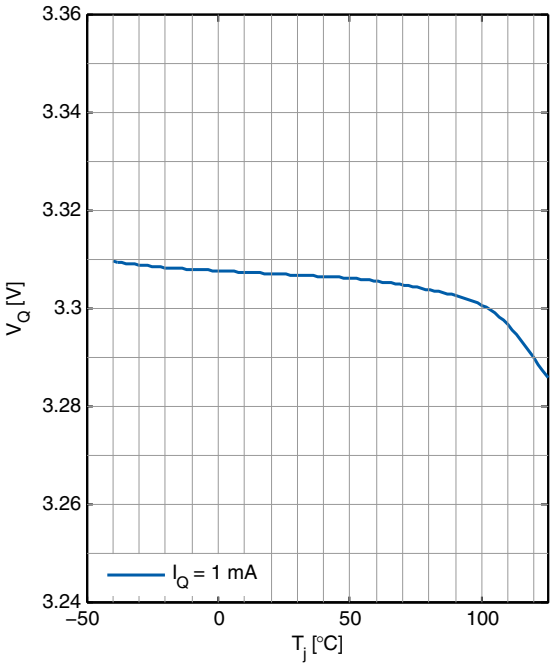
Dropout Voltage V_{DR} versus Junction Temperature T_j



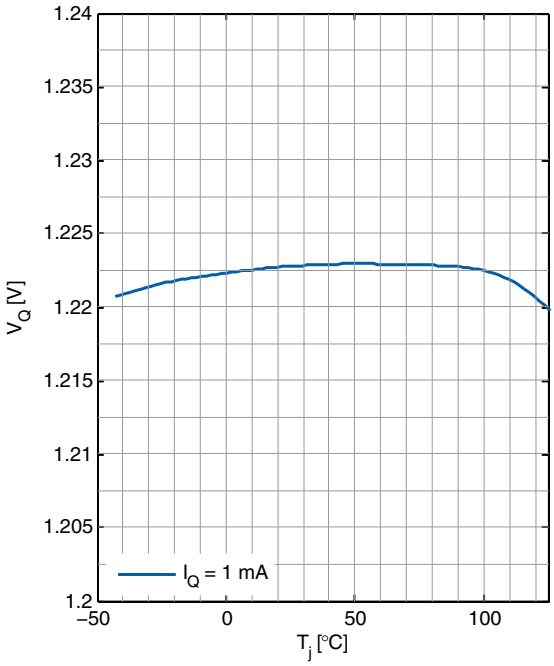
Quiescent Current versus Junction Temperature T_j



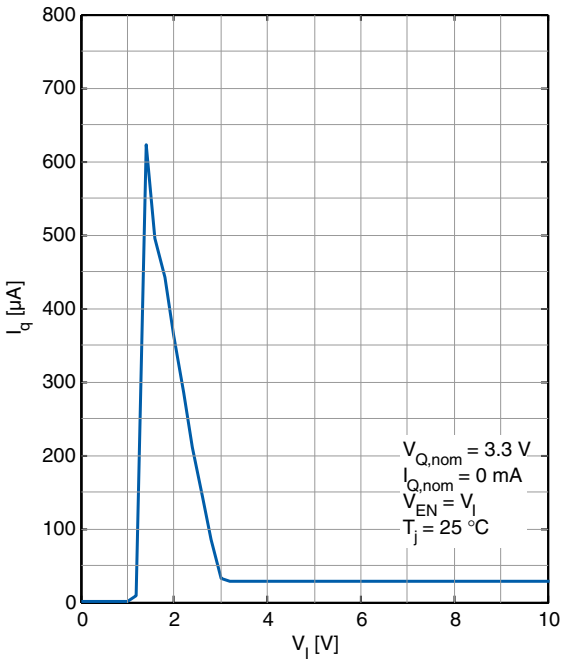
Output Voltage V_Q versus Junction Temperature T_J (TLS205B0EJV33)



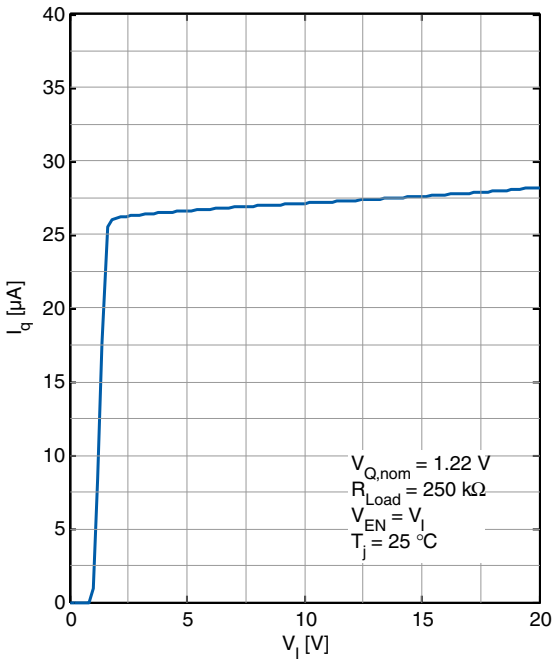
Output Voltage V_Q versus Junction Temperature T_J (TLS205B0EJV)



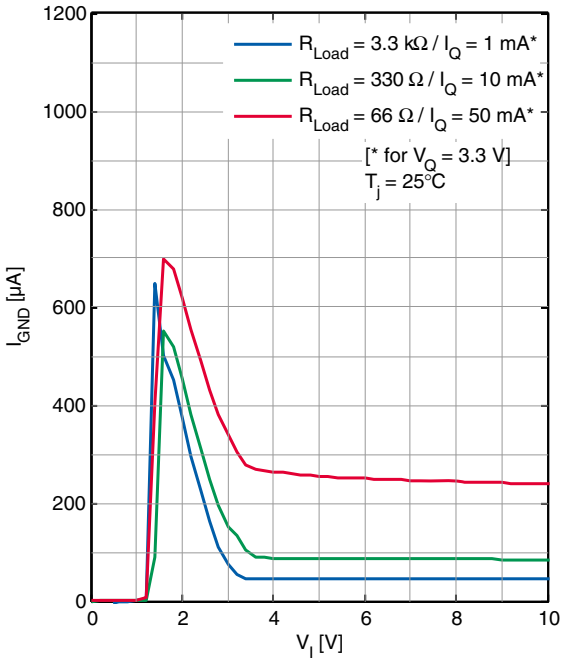
Quiescent Current I_q versus Input Voltage V_I (TLS205B0EJV33)



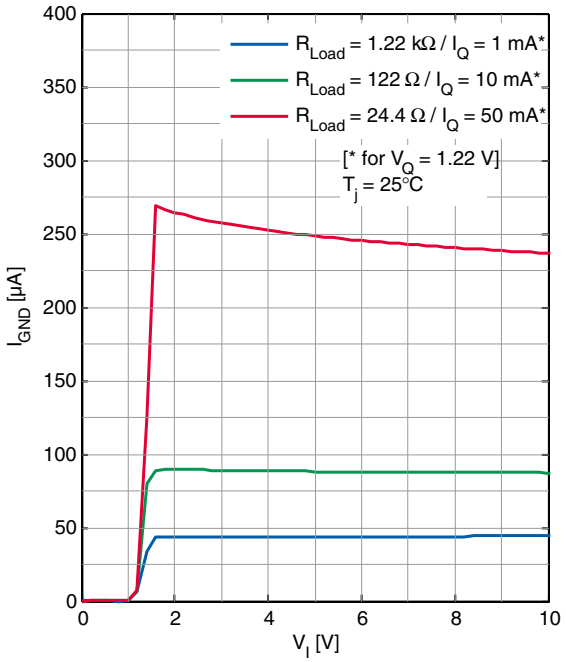
Quiescent Current I_q versus Input Voltage V_I (TLS205B0EJV)



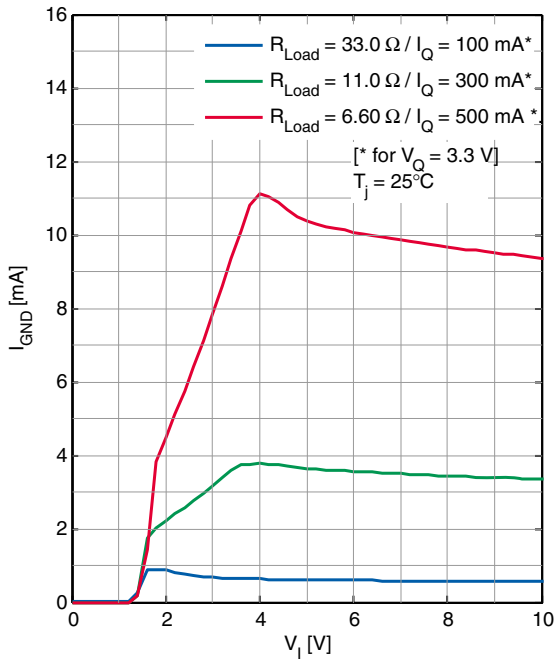
GND Pin Current I_{GND} versus Input Voltage V_I (TLS205B0EJV33)



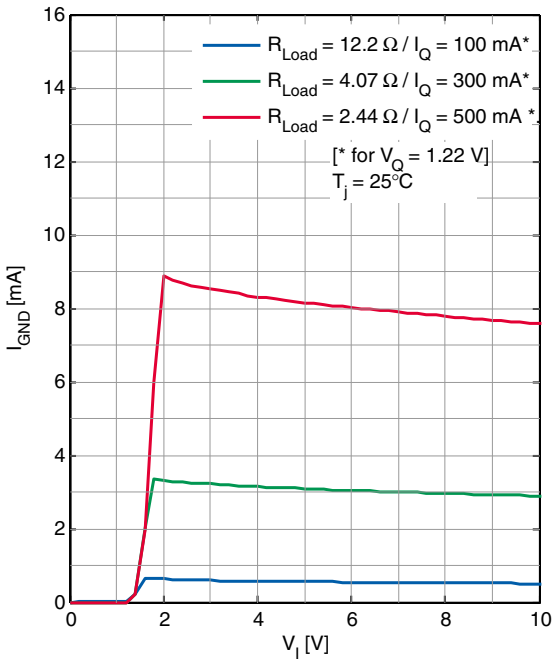
GND Pin Current I_{GND} versus Input Voltage V_I (TLS205B0EJV)



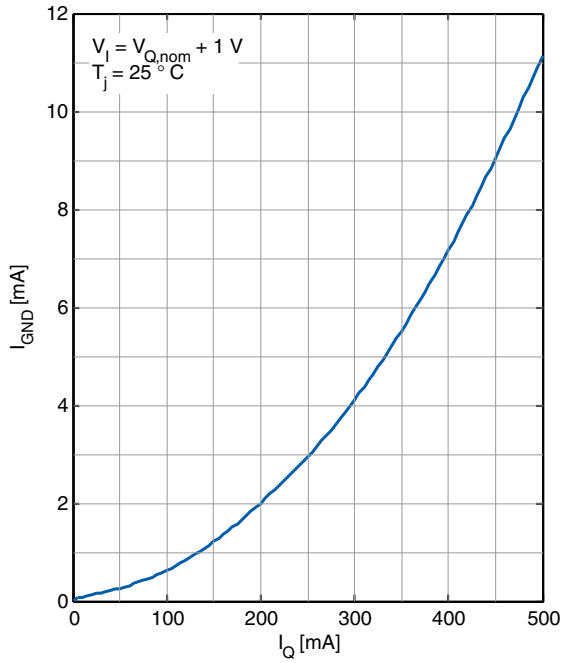
GND Pin Current I_{GND} versus Input Voltage V_I (TLS205B0EJV33)



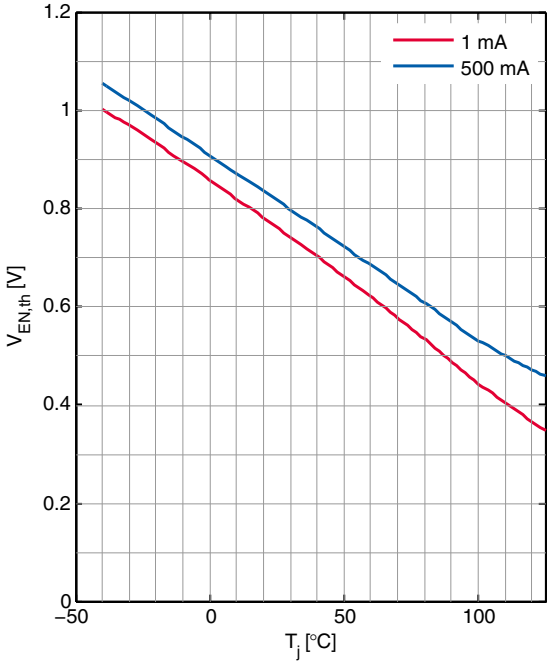
GND Pin Current I_{GND} versus Input Voltage V_I (TLS205B0EJV)



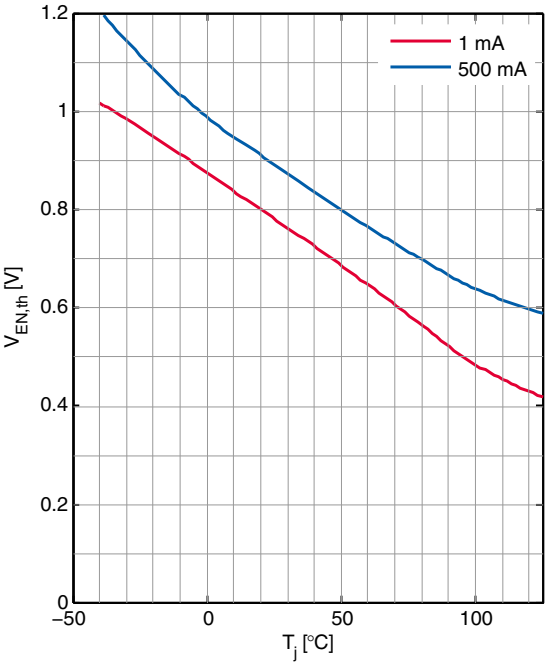
GND Pin Current I_{GND} versus Output Current I_Q



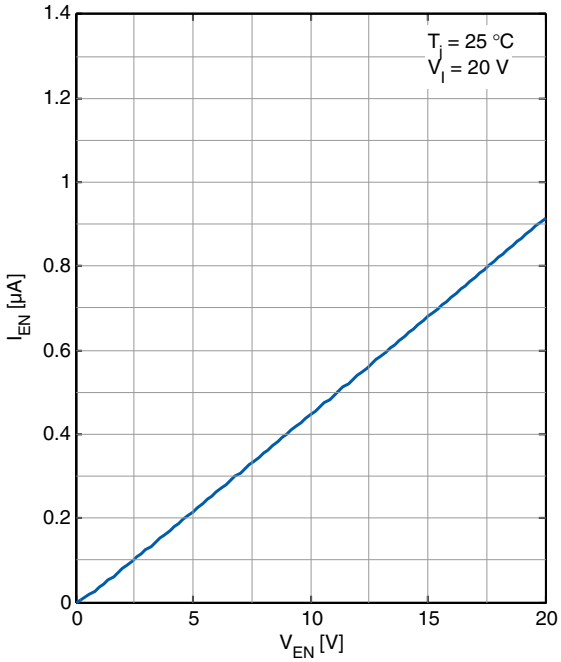
EN Pin Threshold (On-to-Off) versus Junction Temperature T_J



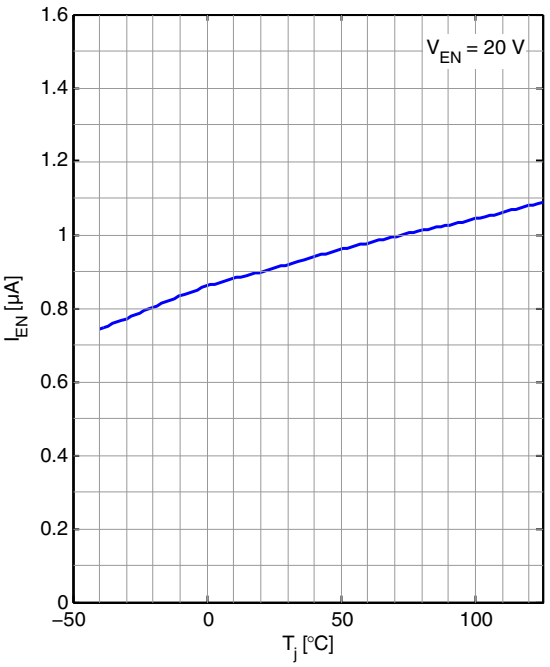
EN Pin Threshold (Off-to-On) versus Junction temperature T_J



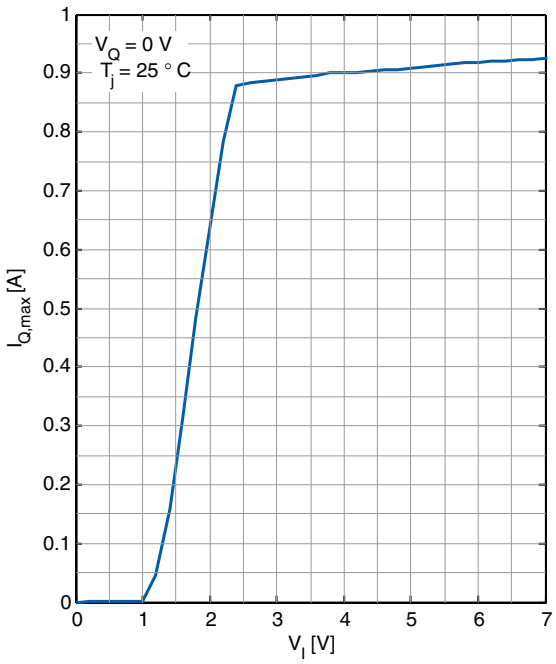
EN Pin Input Current (On-to-Off) versus EN Pin Voltage V_{EN}



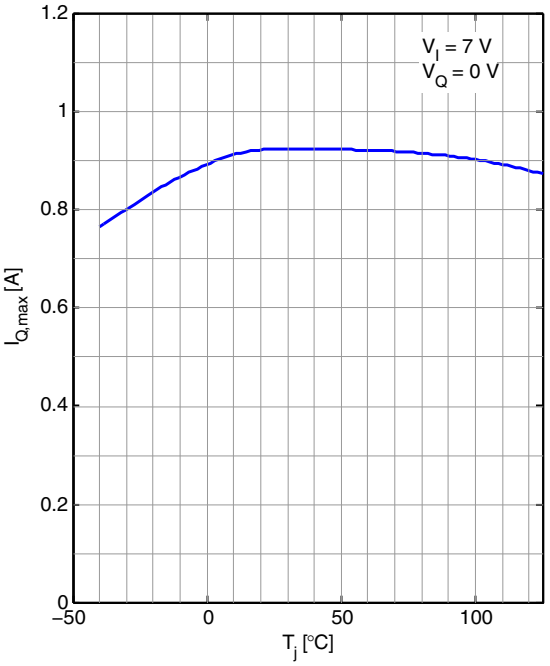
EN Pin Current versus Junction Temperature T_J



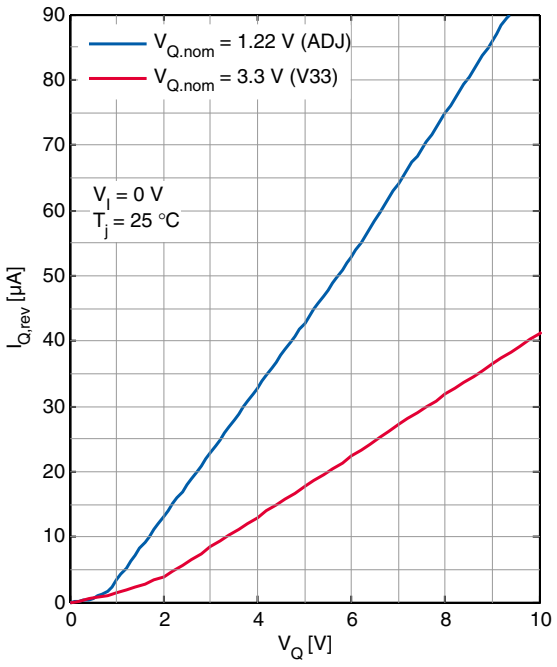
Current Limit versus Input Voltage V_I



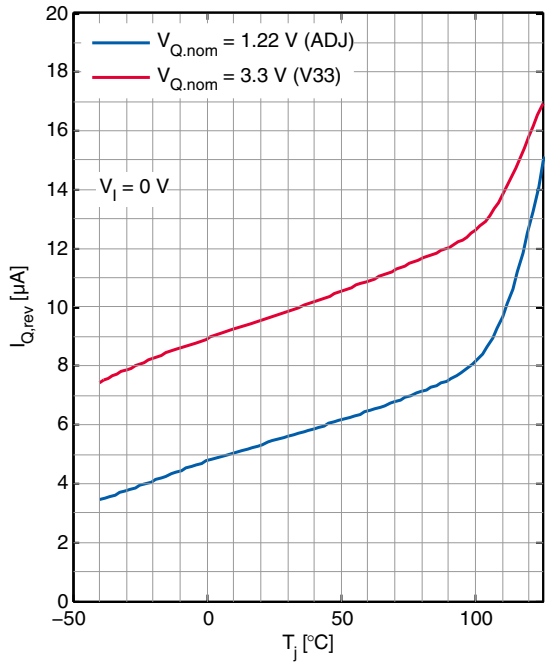
Current Limit versus Junction Temperature T_J



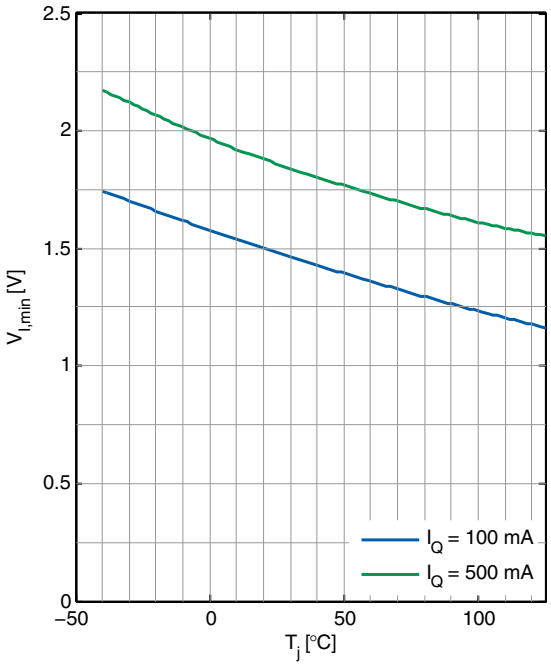
Reverse Output Current versus Output Voltage V_Q



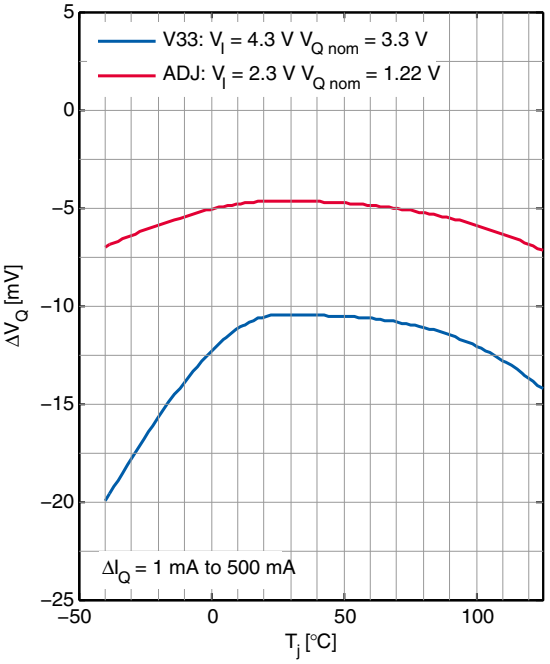
Reverse Output Current versus Junction Temperature T_J



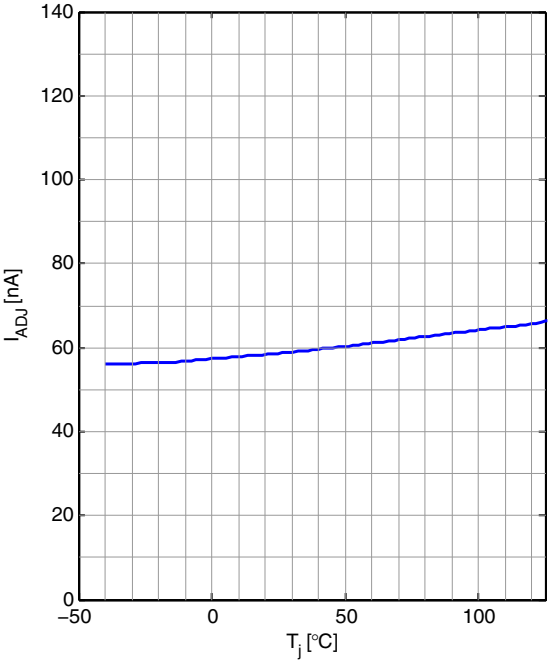
Minimum Input Voltage [1] versus Junction Temperature T_J



Load Regulation versus Junction Temperature T_J

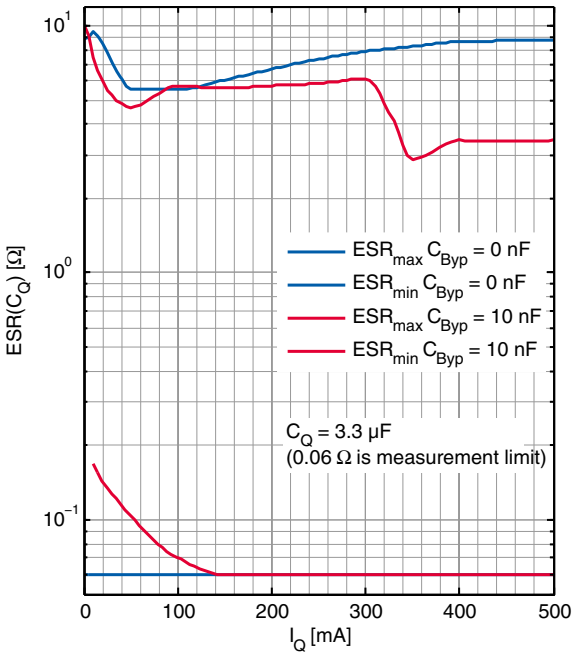


Adjust Pin Bias Current versus Junction Temperature T_J

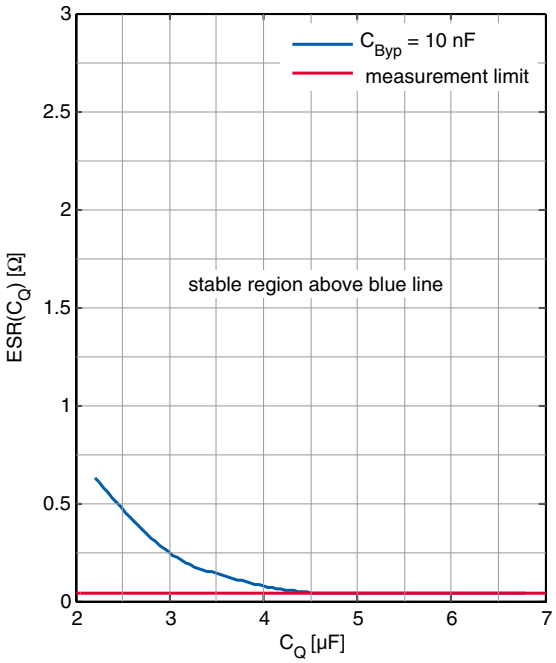


1) $V_{I,min}$ is referred here as the minimum input voltage for which the requested current is provided and V_Q reaches 1 V.

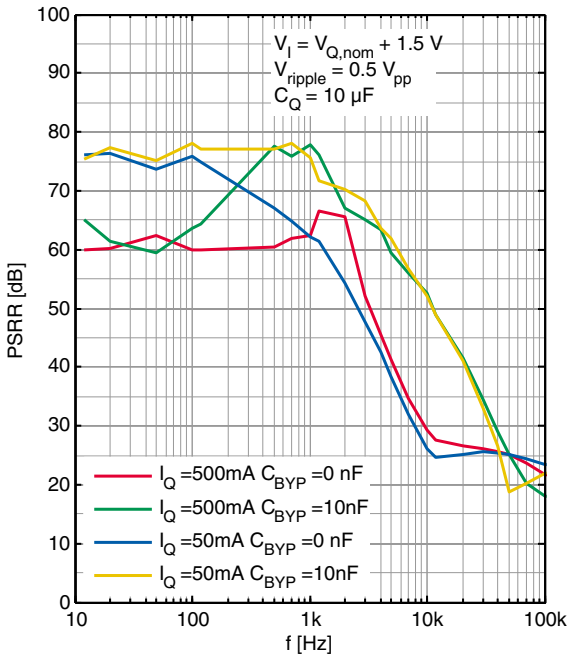
ESR Stability versus Output Current I_Q (for C_Q = 3.3 µF)



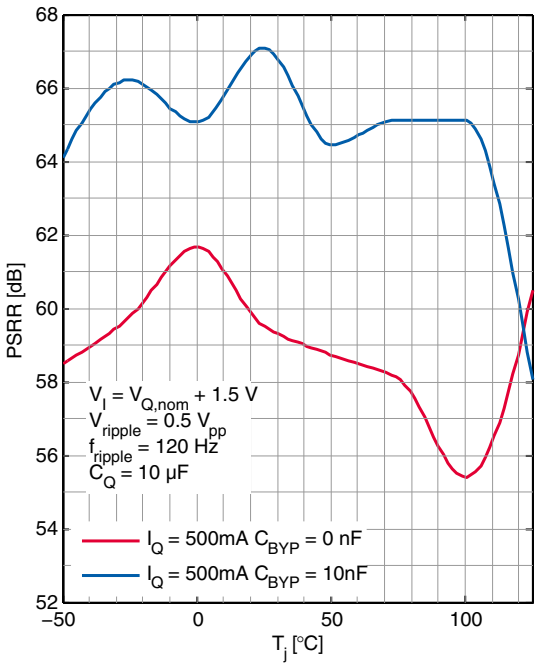
ESR(C_Q) with C_{BYP} = 10 nF versus Output Capacitance C_Q



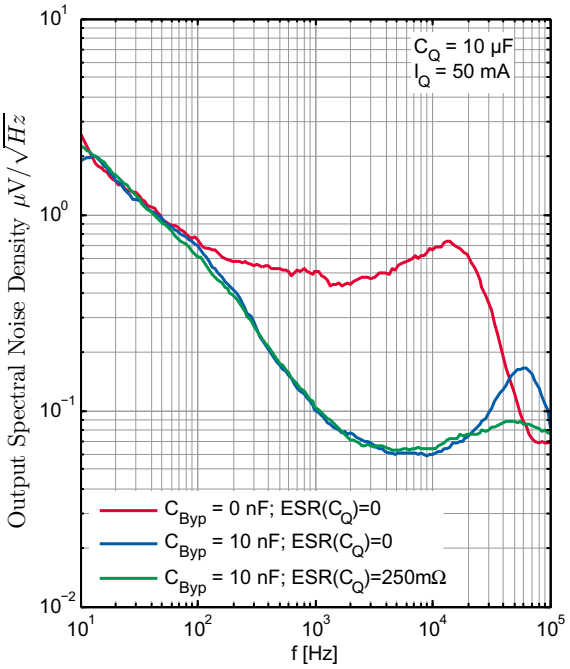
Input Ripple Rejection PSRR versus Frequency f



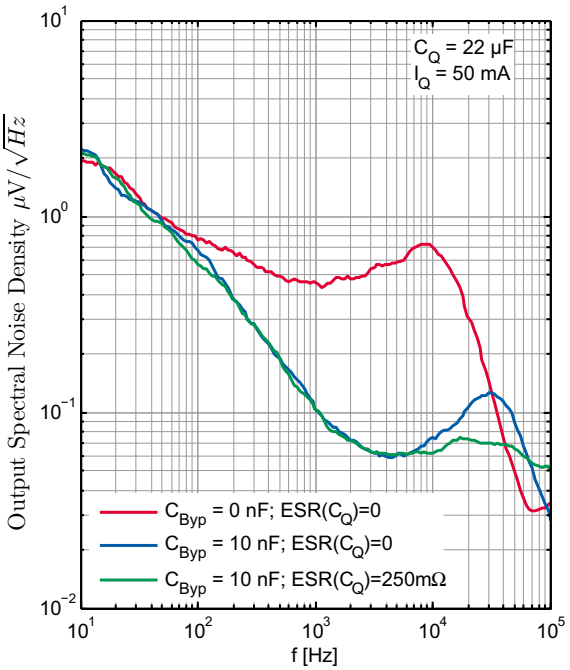
Input Ripple Rejection PSRR versus Junction Temperature T_J



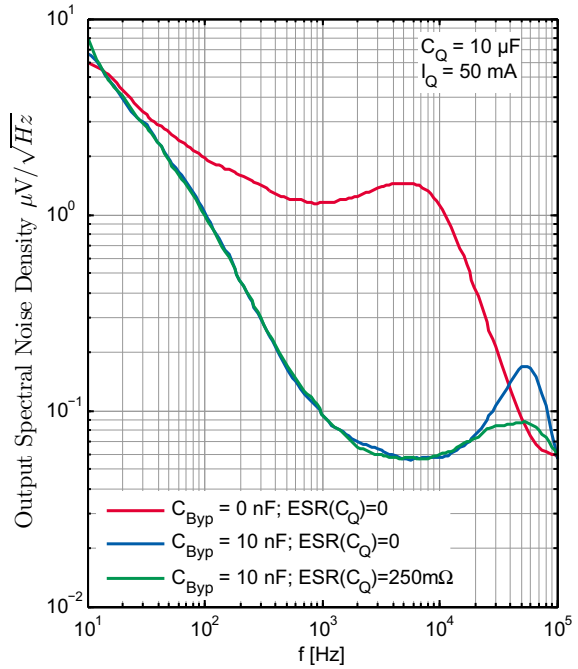
Output Noise Spectral Density (ADJ) versus Frequency f (C_Q = 10 µF, I_Q = 50 mA)



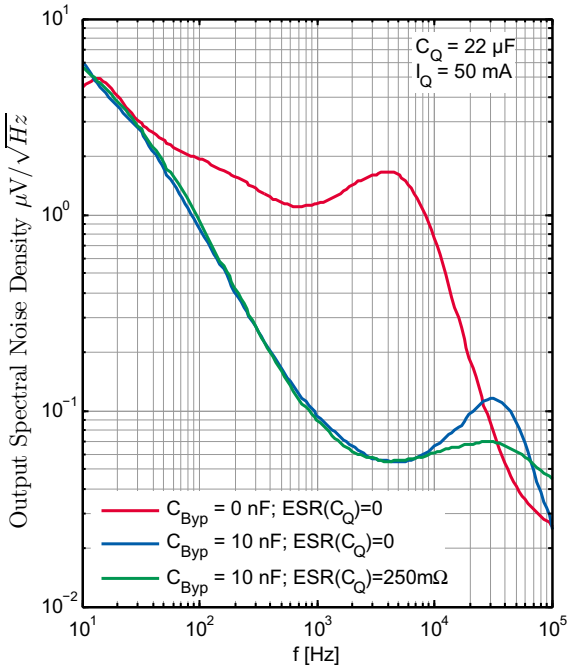
Output Noise Spectral Density (ADJ) versus Frequency f (C_Q = 22 µF, I_Q = 50 mA)



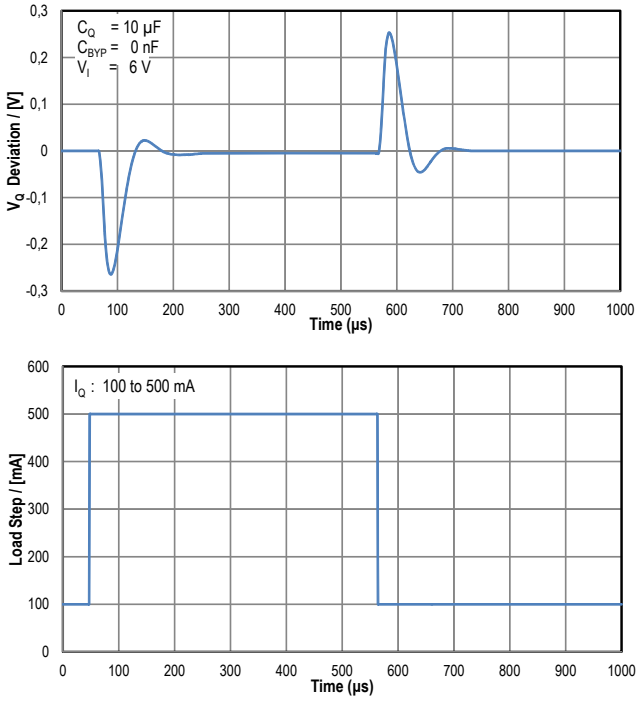
Output Noise Spectral Density (3.3V) versus Frequency f (C_Q = 10 µF, I_Q = 50 mA)



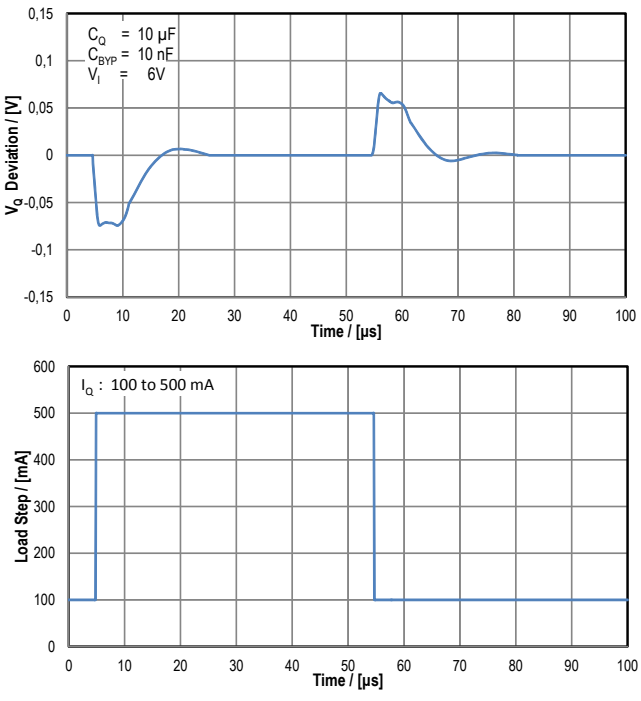
Output Noise Spectral Density (3.3V) versus Frequency f (C_Q = 22 µF, I_Q = 50 mA)



Transient Response C_{BYP}= 0 nF (TLS205B0EJV33)



Transient Response C_{BYP}= 10 nF (TLS205B0EJV33)



6 Application Information

Note: The following information is given as a hint for the implementation of the device only and shall not be regarded as a description or warranty of a certain functionality, condition or quality of the device.

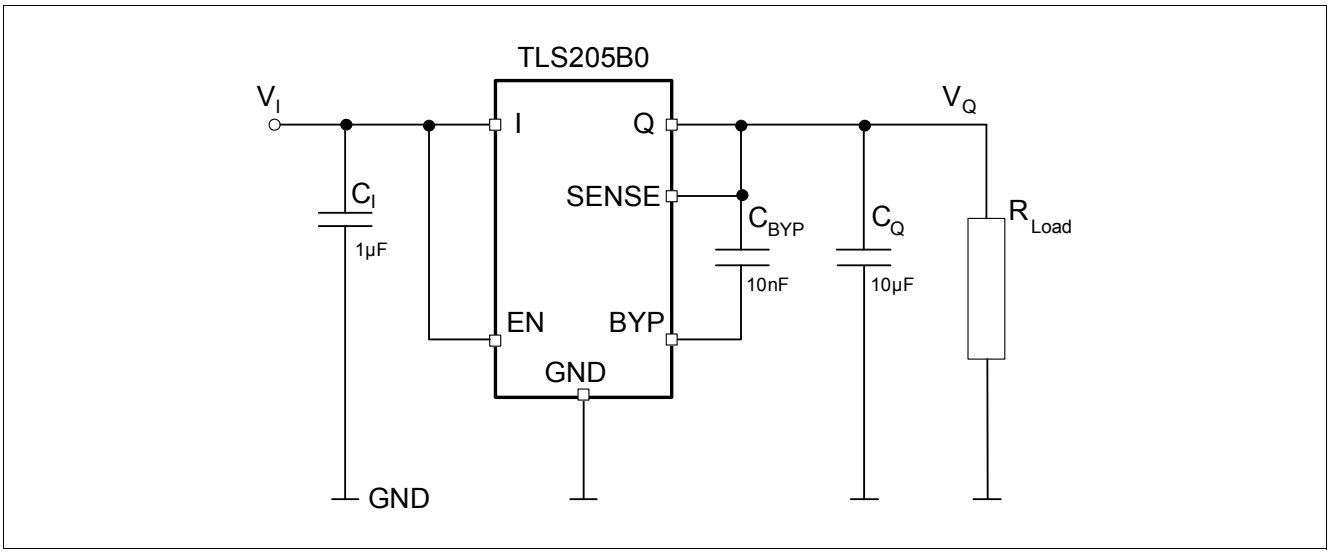


Figure 5 Typical Application Circuit TLS205B0 (fixed voltage version)

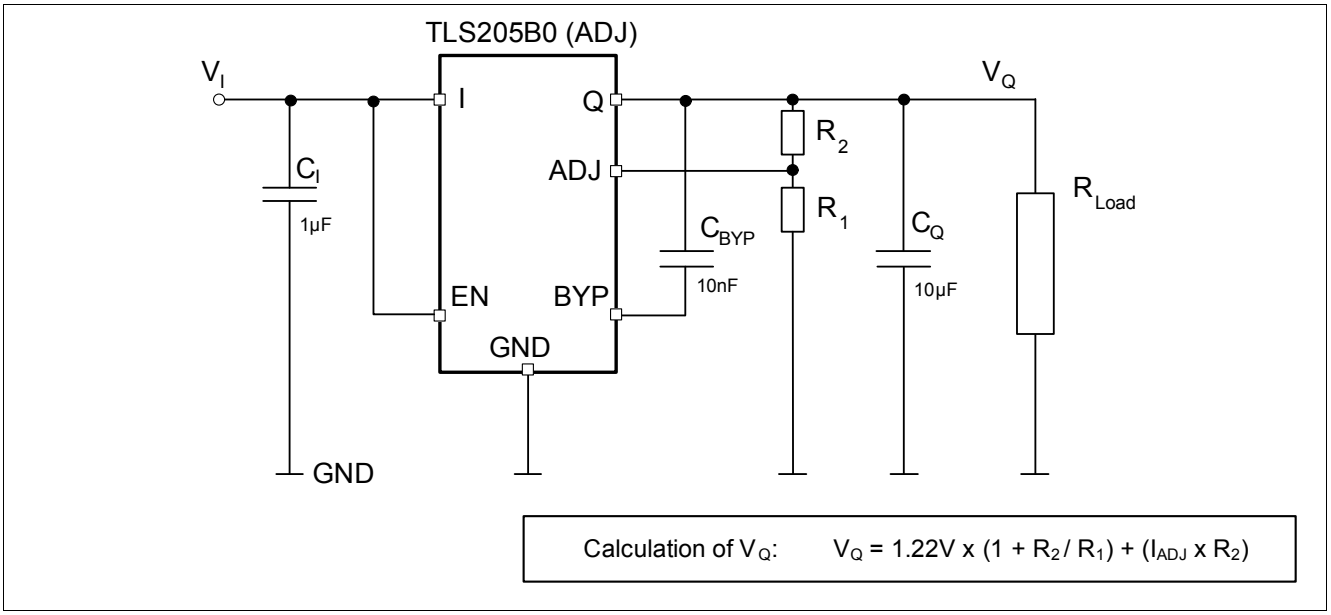


Figure 6 Typical Application Circuit TLS205B0 (adjustable version)

Note: This is a very simplified example of an application circuit. The function must be verified in the real application. [1) 2)]

1) Please note that in case a non-negligible inductance at the input pin I is present, e.g. due to long cables, traces, parasitics, etc, a bigger input capacitor C_I may be required to filter its influence. As a rule of thumb if the I pin is more than six inches away from the main input filter capacitor an input capacitor value of C_I = 10 µF is recommended.

2) For specific needs a small optional resistor may be placed in series to very low ESR output capacitors C_Q for enhanced noise performance (for details please see **"Bypass Capacitance and Low Noise Performance" on Page 25**).

The TLS205B0 is a 500 mA low dropout regulator with very low quiescent current and Enable-functionality. The device is capable of supplying 500 mA at a dropout voltage of 320 mV. Output voltage noise numbers down to 24 μV_{RMS} can be achieved over a 10 Hz to 100 kHz bandwidth with the addition of a 10 nF reference bypass capacitor. The usage of a reference bypass capacitor will additionally improve transient response of the regulator, lowering the settling time for transient load conditions. The device has a low operating quiescent current of typical 30 µA that drops to less than 1 µA in shutdown (EN-pin pulled to low level). The device also incorporates several protection features which makes it ideal for battery-powered systems. It is protected against both reverse input and reverse output voltages.

6.1 Adjustable Operation

The adjustable version of the TLS205B0 has an output voltage range of 1.22 V to 20 V - V_{DR}. The output voltage is set by the ratio of two external resistors, as it can be seen in **Figure 6**. The device controls the output to maintain the ADJ pin at 1.22 V referenced to ground. The current in R1 is then equal 1.22 V / R1 and the current in R2 equals the current in R1 plus the ADJ pin bias current. The ADJ pin bias current, which is ~60 nA @ 25 °C, flows through R2 into the ADJ pin. The value of R1 should be not greater than 250 kΩ in order to minimize errors in the output voltage caused by the ADJ pin bias current. Note that when the device is shutdown (i.e. low level applied to EN pin) the output is turned off and consequently the divider current will be zero. For details of the ADJ Pin Bias current see also the corresponding typical performance graph **“Adjust Pin Bias Current versus Junction Temperature T_J” on Page 20**.

6.2 Kelvin Sense Connection

For the fixed voltage version of the TLS205B0 the SENSE pin is the input to the error amplifier. An optimum regulation will be obtained at the point where the SENSE pin is connected to the output pin Q of the regulator. In critical applications however small voltage drops may be caused by the resistance R_p of the PC-traces and thus may lower the resulting voltage at the load. This effect may be eliminated by connecting the SENSE pin to the output as close as possible at the load (see **Figure 7**). Please note that the voltage drop across the external PC trace will add up to the dropout voltage of the regulator.

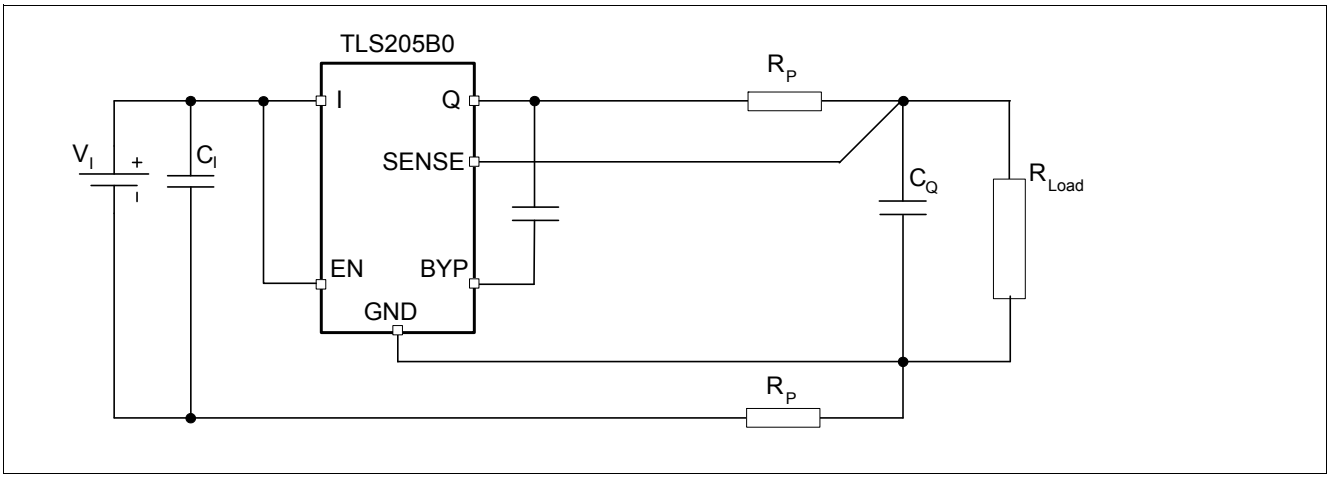


Figure 7 Kelvin Sense Connection

6.3 Bypass Capacitance and Low Noise Performance

The TLS205B0 regulator may be used in combination with a bypass capacitor connecting the output pin Q to the BYP pin in order to minimize output voltage noise [1]. This capacitor will bypass the reference of the regulator, providing a low frequency noise pole. The noise pole provided by such a bypass capacitor will lower the output

1) a good quality low leakage capacitor is recommended.